TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC7MZ245FK

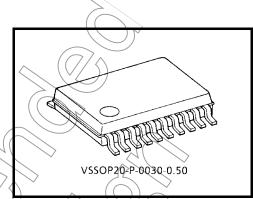
Low Voltage Octal Bus Transceiver with 5 V Tolerant Inputs and Outputs

The TC7MZ245FK is a high performance CMOS octal bus transceiver. Designed for use in 3.3 V systems, it achieves high speed operation while maintaining the CMOS low power dissipation.

The device is designed for low-voltage (3.3 V) $V_{\rm CC}$ applications, but it could be used to interface to 5 V supply environment for both inputs and outputs.

The direction of data transmission is determined by the level of the DIR input. The enable input ($\overline{\rm OE}$) can be used to disable the device so that the busses are effectively isolated.

All inputs are equipped with protection circuits against static discharge.



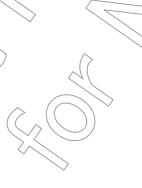
Weight: 0.03 g (typ.)

Features

- Low voltage operation: $V_{CC} = 2.0 \sim 3.6 \text{ V}$
- High speed operation: $t_{pd} = 7.0 \text{ ns (max)} (V_{CC} = 3.0 3.6 \text{ V})$
- Output current: | IOH | /IOL = 24 mA (min) (VCC = 3.0 V)
- Latch-up performance: -500 mA
- Package: VSSOP (US20)
- Bidirectional interface between 3.3 V and 5.0 V signals.
- Power down protection is provided on all inputs and outputs.
- Pin and function compatible with the 74 series (74AC/VHC/HC/E/ALS/LS etc.) 245 type.

Note: Do not apply a signal to any bus terminal when it is in the output mode. Damage may result.

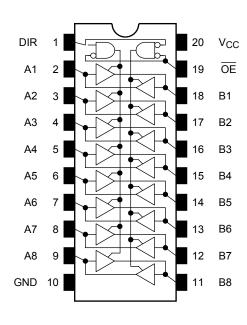
All floating (high impedance) bus terminals must have their input levels fixed by means of pull up or pull down resistors.

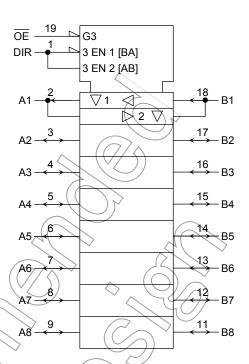


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Pin Assignment (top view)

IEC Logic Symbol





Truth Table

| Inputs | | Outputs | Function | | | |
|--------|-----|---------|----------|---------|--|--|
| ŌĒ | DIR | Outputs | A-Bus | B-Bus | | |
| L | L | A = B | Qutput | Input | | |
| L | Н | B = A | Input | Output | | |
| Н | Х | z | High Im | pedance | | |

X: Don't care

Z: High impedance



Absolute Maximum Ratings (Note 1)

| Characteristics | Characteristics Symbol Rating | | Unit | |
|---|-----------------------------------|-------------------------------------|-----------|--|
| Supply voltage range | V _{CC} | -0.5~7.0 | V | |
| DC input voltage (DIR, $\overline{\text{OE}}$) | V _{IN} | -0.5~7.0 | ٧ | |
| DC bus I/O voltage | \/a | -0.5~7.0 (Note 2) | V | |
| DC bus I/O voltage | V _{I/O} | -0.5~V _{CC} + 0.5 (Note 3) | \ \ \ \ \ | |
| Input diode current | l _{IK} | -50 | mA (| |
| Output diode current | I _{OK} | ±50 (Note 4) | mA | |
| DC output current | lout | ±50 | (mA/ < | |
| Power dissipation | P_{D} | 180 | mW | |
| DC V _{CC} /ground current | I _{CC} /I _{GND} | ±100 | mA | |
| Storage temperature | T _{stg} | -65~150 | Je | |

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in 10 performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 2: Output in off-state

Note 3: High or low state. IOUT absolute maximum rating must be observed.

Note 4: $V_{OUT} < GND, V_{OUT} > V_{CC}$

Operating Ranges (Note 1)

| Characteristics | Symbol | Rating | Unit | |
|--------------------------|------------------|---|------|--|
| Supply voltage | V _{CC} | 2,0 ₇ 3.6 1.5 ₇ 3.6 (Note 2) | V | |
| Input voltage (DIR, OE) | V _{IN} | 0~5.5 | V | |
| Bus I/O voltage | Viia | 0~5.5 (Note 3) | V | |
| Bus I/O voltage | V _{I/O} | 0~V _{CC} (Note 4) | V | |
| Output ourront | Ioh/IoL | ±24 (Note 5) | m^ | |
| Output current | IOH/IOL | ±12 (Note 6) | mA | |
| Operating temperature | Topr | -40~85 | °C | |
| Input rise and fall time | dt/dv | 0~10 (Note 7) | ns/V | |

Note 1: The operating ranges must be maintained to ensure the normal operation of the device. Unused inputs and bus inputs must be tied to either VCC or GND. Please connect both bus inputs and the bus outputs with VCC or GND when the I/O of the bus terminal changes by the function. In this case, please note that the output is not short-circuited.

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Note 2: Data retention only

Note 3: Output in off-state

Note 4: High or low state

Note 5: $V_{CC} = 3.0 \sim 3.6 \text{ V}$

Note 6: $V_{CC} = 2.7 \sim 3.0 \text{ V}$

Note 7: $V_{IN} = 0.8 \sim 2.0 \text{ V}, V_{CC} = 3.0 \text{ V}$

Electrical Characteristics

DC Characteristics ($Ta = -40 \sim 85$ °C)

| Characte | eristics | Symbol | Test (| Condition | V _{CC} (V) | Min | Max | Unit |
|-------------------------------|-----------------|-----------------------|--|--------------------------|--------------------------|-------|-------|------|
| lancet college | High level | V_{IH} | | _ | 2.7~3.6 | 2.0 | _ | V |
| Input voltage | Low level | V _{IL} | | _ | 2.7~3.6 | _ | 0.8 | V |
| | | | I _{OH} = -100 μA | 2.7~3.6 | V _{CC} - 0.2 | _ | | |
| | High level | V _{OH} | V _{IN} = V _{IH} or V _{IL} | I _{OH} = -12 mA | 2.7 | 2.2 | _ | V |
| | | | | I _{OH} = -18 mA | 3.0 | 2.4 | _ | |
| Output voltage | | | | I _{OH} = -24 mA | 3.0 | 2.2 | _ | |
| Low level | | level V _{OL} | V _{IN} = V _{IH} or V _{IL} | I _{OL} = 100 μA | 2.7~3.6 | | 0.2 | |
| | I ow level | | | I _{OL} = 12 mA | 2.7 | 4 | 0.4 | |
| | LOW level | | | I _{OL} = 16 mA | 3.0 | > /=/ | 0.4 | |
| | | | | I _{OL} = 24 mA) | 3.0 | | 0.55 | |
| Input leakage cu | ırrent | I _{IN} | V _{IN} = 0~5.5 V | | 2.7~3.6 | (4) | ±5.0 | μΑ |
| 3-state output of | f-state current | l _{OZ} | $V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{OUT} = 0 \sim 5.5 \text{ V}$ | | 2.7~3.6 | > _ | ±5.0 | μΑ |
| Power off leakage | ge current | l _{OFF} | V _{IN} /V _{OUT} = 5.5 V | | 0 | _ | 10.0 | μА |
| Quicecent august | v ourront | laa | V _{IN} = V _{CC} or GND | | 2.7~3.6 | _ | 10.0 | |
| Quiescent suppl | y current | Icc | V _{IN} /V _{OUT} = 3.6~5.5 V | | 2.7~3.6 | _ | ±10.0 | μΑ |
| Increase in I _{CC} p | per input | Δlcc | V _{IH} = V _{CC} - 0.6 V | | 2.7~3.6 | _ | 500 | |

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AC Characteristics ($Ta = -40 \sim 85$ °C)

| Characteristics | Symbol | Test Condition | V _{CC} (V) | Min | Max | Unit |
|------------------------|-------------------|--------------------|---------------------|-------|-----|------|
| Propagation delay time | t _{pLH} | Figure 1, Figure 2 | 2.7 | _ | 8.0 | ns |
| Fropagation delay time | t _{pHL} | rigure i, rigure 2 | 3.3 ± 0.3 | 1.5 | 7.0 | 115 |
| Output enable time | t _{pZL} | Figure 1, Figure 3 | 2.7 | | 9.5 | ns |
| Output enable time | t _{pZH} | | 3(3(± 0.3) | 1.5 | 8.5 | 110 |
| Output disable time | t _{pLZ} | Figure 1, Figure 3 | 2.7 |) | 8.5 | ns |
| Output disable time | t _{pHZ} | rigure 1, rigure 3 | 3.3 0.3 | 1.5 | 7.5 | 119 |
| Output to output skew | t _{osLH} | (Note) | 2.1 | | | ns |
| | t _{osHL} | (male) | 3.3 ± 0.3 | _ | 1.0 | 113 |

Note: This parameter is guaranteed by design.

 $(t_{OSLH} = |t_{pLHm} - t_{pLHn}|, t_{OSHL} = |t_{pHLm} - t_{pHLn}|)$

Dynamic Switching Characteristics

(Ta = 25°C, Input: $t_r = t_f = 2.5$ ns, $C_L = 50$ pF, $R_L = 500$ Ω

| | | | 9(// | | |
|--|------------------|--|---------------------|------|------|
| Characteristics | Symbol | Test Condition | V _{CC} (V) | Тур. | Unit |
| Quiet output maximum dynamic V _{OL} | V _{OLP} | $V_{IH} = 3.3 V$, $V_{IL} = 0 V$ | 3.3 | 8.0 | V |
| Quiet output minimum dynamic V _{OL} | V _{OLV} | V _{IH} = 3.3 V, V _{IL} = 0 V | 3.3 | 8.0 | ٧ |

Capacitive Characteristics (Ta = 25°C)

| Characteristics | Symbol | Test Condition | V _{CC} (V) | Тур. | Unit |
|-------------------------------|--------|---------------------------------|---------------------|------|------|
| Input capacitance | CIN | DIR, OE | 3.3 | 7 | pF |
| Bus input capacitance | Cho | A _n , B _n | 3.3 | 8 | pF |
| Power dissipation capacitance | CPD | f _{IN} = 10 MHz (Note) | 3.3 | 25 | pF |

Note: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption.

Average operating current can be obtained by the equation:

ICC (opr) = CPD·VCC·fIN + ICC/8 (per bit)



AC Test Circuit

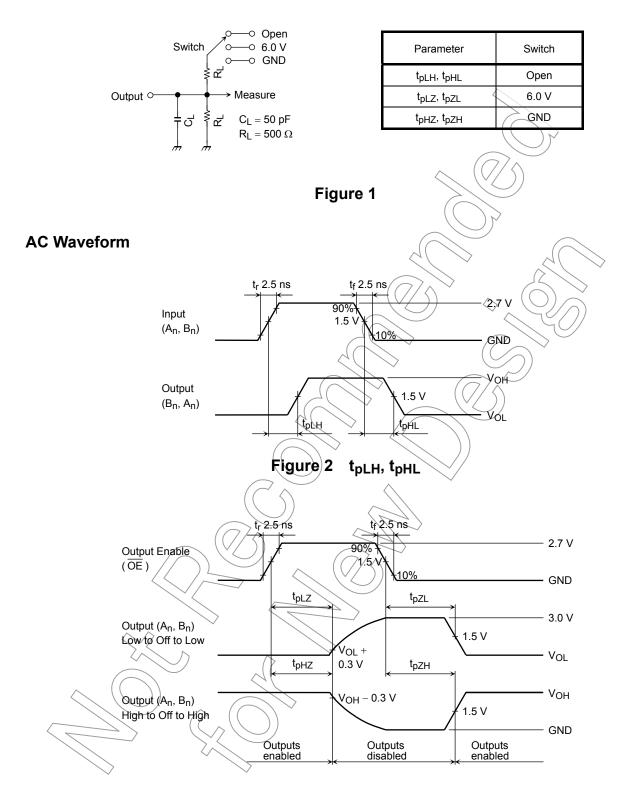
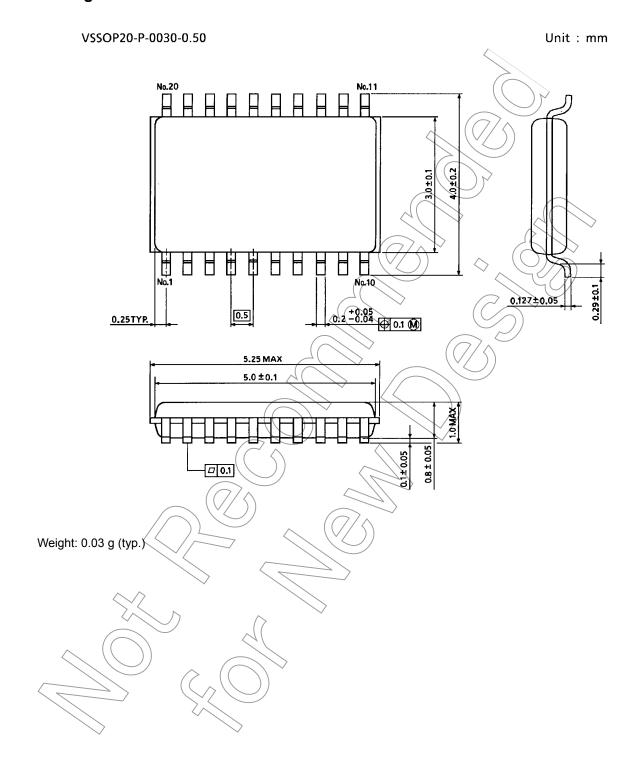


Figure 3 t_{pLZ} , t_{pHZ} , t_{pZL} , t_{pZH}

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Package Dimensions



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